



Thyristor/Diode and Thyristor/Thyristor (ADD-A-PAK™ Generation 5 Power Modules), 45/60 A



ADD-A-PAK™

PRODUCT SUMMARY	
$I_{T(AV)}$ or $I_{F(AV)}$	45/60 A

MECHANICAL DESCRIPTION

The Generation 5 of ADD-A-PAK™ modules combine the excellent thermal performance obtained by the usage of Direct Bonded Copper substrate with superior mechanical ruggedness, thanks to the insertion of a solid copper baseplate at the bottom side of the device. The Cu baseplate allows an easier mounting on the majority of heatsink with increased tolerance of surface roughness and improved thermal spread. The Generation 5 of AAP modules is manufactured without hard mold, eliminating in this way any possible direct stress on the leads.

The electrical terminals are secured against axial pull-out: they are fixed to the module housing via a click-stop feature already tested and proved as reliable on other Vishay HPP modules.

FEATURES

- High voltage
- Industrial standard package
- Thick copper baseplate
- UL E78996 approved
- 3500 V_{RMS} isolating voltage
- Totally lead (Pb)-free
- Designed and qualified for industrial level



RoHS
COMPLIANT

BENEFITS

- Up to 1600 V
- Fully compatible TO-240AA
- High surge capability
- Easy mounting on heatsink
- Al₂O₃ DBC insulator
- Heatsink grounded

ELECTRICAL DESCRIPTION

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VSK.41	VSK.56	UNITS
$I_{T(AV)}$ or $I_{F(AV)}$	85 °C	45	60	A
$I_{O(RMS)}$	As AC switch	100	135	
I_{TSM} , I_{FSM}	50 Hz	850	1310	
	60 Hz	890	1370	
I^2t	50 Hz	3.61	8.50	kA ² s
	60 Hz	3.30	7.82	
$I^2\sqrt{t}$		36.1	85.0	kA ² √s
V_{RRM}	Range	400 to 1600		V
T_{Stg}		- 40 to 125		°C
T_J				

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ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM REPETITIVE PEAK OFF-STATE VOLTAGE, GATE OPEN CIRCUIT V	I _{RRM} , I _{IDRM} AT 125 °C mA
VSK.41/.56	04	400	500	400	15
	06	600	700	600	
	08	800	900	800	
	10	1000	1100	1000	
	12	1200	1300	1200	
	14	1400	1500	1400	
	16	1600	1700	1600	

ON-STATE CONDUCTION							
PARAMETER	SYMBOL	TEST CONDITIONS			VSK.41	VSK.56	UNITS
Maximum average on-state current (thyristors)	I _{T(AV)}	180° conduction, half sine wave, T _C = 85 °C			45	60	
Maximum average forward current (diodes)	I _{F(AV)}						
Maximum continuous RMS on-state current, as AC switch	I _{O(RMS)}				100	135	
Maximum peak, one-cycle non-repetitive on-state or forward current	I _{TSM} or I _{FSM}	t = 10 ms	No voltage reapplied	Sinusoidal half wave, initial T _J = T _J maximum	850	1310	A
		t = 8.3 ms			890	1370	
		t = 10 ms	100 % V _{RRM} reapplied		715	1100	
		t = 8.3 ms			750	1150	
		t = 10 ms	T _J = 25 °C, no voltage reapplied		940	1450	
		t = 8.3 ms			985	1520	
Maximum I ² t for fusing	I ² t	t = 10 ms	No voltage reapplied	Initial T _J = T _J maximum	3.61	8.56	kA ² s
		t = 8.3 ms			3.30	7.82	
		t = 10 ms	100 % V _{RRM} reapplied		2.56	6.05	
		t = 8.3 ms			2.33	5.53	
		t = 10 ms	T _J = 25 °C, no voltage reapplied		4.42	10.05	
		t = 8.3 ms			4.03	9.60	
Maximum I ² √t for fusing	I ² √t (1)	t = 0.1 to 10 ms, no voltage reapplied			36.1	85.6	kA ² √s
Maximum value or threshold voltage	V _{T(TO)} (2)	Low level (3)	T _J = T _J maximum		0.88	0.85	V
		High level (4)			0.91	0.88	
Maximum value of on-state slope resistance	r _t (2)	Low level (3)	T _J = T _J maximum		5.90	3.53	mΩ
		High level (4)			5.74	3.41	
Maximum peak on-state or forward voltage	V _{TM}	I _{TM} = π × I _{T(AV)}	T _J = 25 °C		1.81	1.54	V
	V _{FM}	I _{FM} = π × I _{F(AV)}					
Maximum non-repetitive rate of rise of turned on current	di/dt	T _J = 25 °C, from 0.67 V _{DRM} , I _{TM} = π × I _{T(AV)} , I _g = 500 mA, t _r < 0.5 μs, t _p > 6 μs			150		A/μs
Maximum holding current	I _H	T _J = 25 °C, anode supply = 6 V, resistive load, gate open circuit			200		mA
Maximum latching current	I _L	T _J = 25 °C, anode supply = 6 V, resistive load			400		

Notes

(1) I²t for time t_x = I²√t × √t_x

(2) Average power = V_{T(TO)} × I_{T(AV)} + r_t × (I_{T(RMS)})²

(3) 16.7 % × π × I_{AV} < I < π × I_{AV}

(4) I > π × I_{AV}



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TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS	VSK.41	VSK.56	UNITS
Maximum peak gate power	P_{GM}		10		W
Maximum average gate power	$P_{G(AV)}$		2.5		
Maximum peak gate current	I_{GM}		2.5		A
Maximum peak negative gate voltage	$-V_{GM}$		10		V
Maximum gate voltage required to trigger	V_{GT}	$T_J = -40\text{ °C}$	Anode supply = 6 V resistive load	4.0	
		$T_J = 25\text{ °C}$		2.5	
		$T_J = 125\text{ °C}$		1.7	
Maximum gate current required to trigger	I_{GT}	$T_J = -40\text{ °C}$	Anode supply = 6 V resistive load	270	mA
		$T_J = 25\text{ °C}$		150	
		$T_J = 125\text{ °C}$		80	
Maximum gate voltage that will not trigger	V_{GD}	$T_J = 125\text{ °C}$, rated V_{DRM} applied	0.25		V
Maximum gate current that will not trigger	I_{GD}	$T_J = 125\text{ °C}$, rated V_{DRM} applied	6		mA

BLOCKING					
PARAMETER	SYMBOL	TEST CONDITIONS	VSK.41	VSK.56	UNITS
Maximum peak reverse and off-state leakage current at V_{RRM} , V_{DRM}	I_{RRM} , I_{DRM}	$T_J = 125\text{ °C}$, gate open circuit	15		mA
RMS insulation voltage	V_{INS}	50 Hz, circuit to base, all terminals shorted	2500 (1 min) 3500 (1 s)		V
Maximum critical rate of rise of off-state voltage	dV/dt ⁽¹⁾	$T_J = 125\text{ °C}$, linear to $0.67 V_{DRM}$	500		V/ μ s

Note

⁽¹⁾ Available with $dV/dt = 1000\text{ V/ms}$, to complete code add S90 i.e. VSKT41/16AS90

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VSK.41	VSK.56	UNITS
Junction operating and storage temperature range	T_J , T_{Stg}		- 40 to 125		°C
Maximum internal thermal resistance, junction to case per module	R_{thJC}	DC operation	0.23	0.20	K/W
Typical thermal resistance, case to heatsink	R_{thCS}	Mounting surface flat, smooth and greased	0.1		
Mounting torque $\pm 10\%$	to heatsink	A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound.	5		Nm
	busbar		3		
Approximate weight			110		g
			4		oz.
Case style		JEDEC	TO-240AA		

ΔR CONDUCTION PER JUNCTION											
DEVICES	SINE HALF WAVE CONDUCTION					RECTANGULAR WAVE CONDUCTION					UNITS
	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	
VSK.41	0.11	0.13	0.17	0.23	0.34	0.09	0.14	0.18	0.23	0.34	°C/W
VSK.56	0.09	0.11	0.13	0.18	0.27	0.07	0.11	0.14	0.19	0.28	

Note

• Table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

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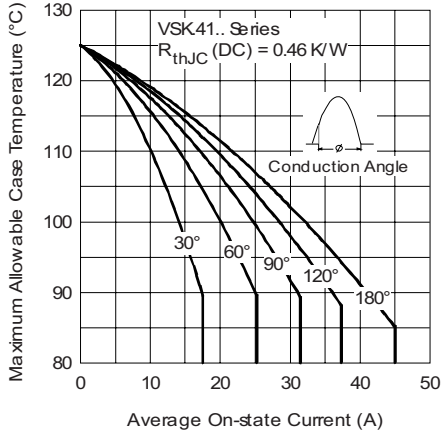


Fig. 1 - Current Ratings Characteristics

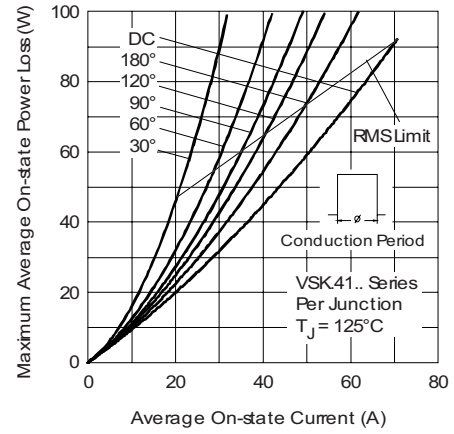


Fig. 4 - On-State Power Loss Characteristics

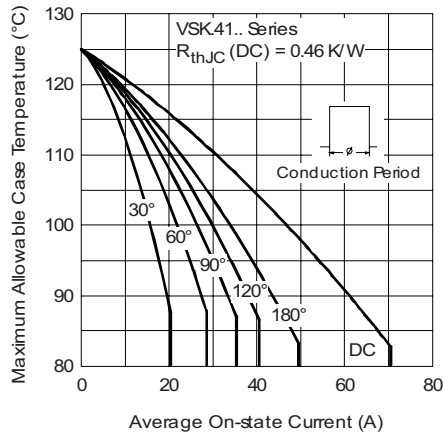


Fig. 2 - Current Ratings Characteristics

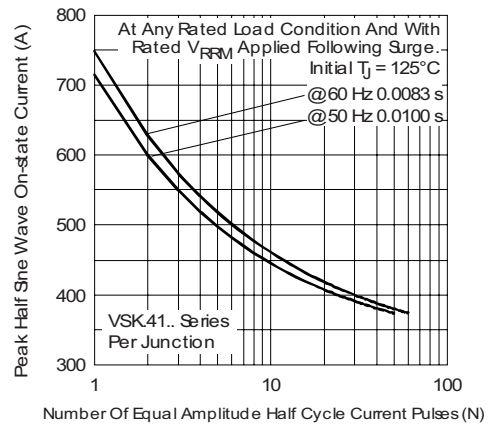


Fig. 5 - Maximum Non-Repetitive Surge Current

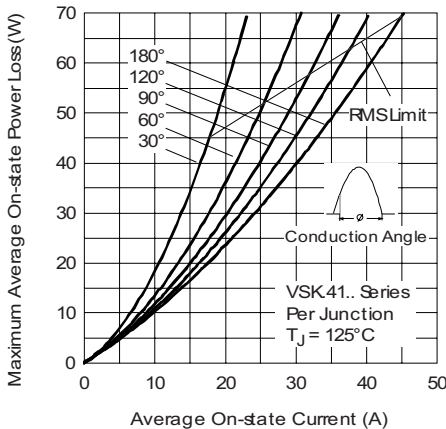


Fig. 3 - On-State Power Loss Characteristics

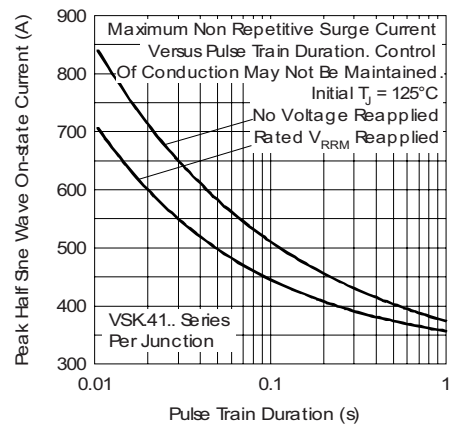


Fig. 6 - Maximum Non-Repetitive Surge Current



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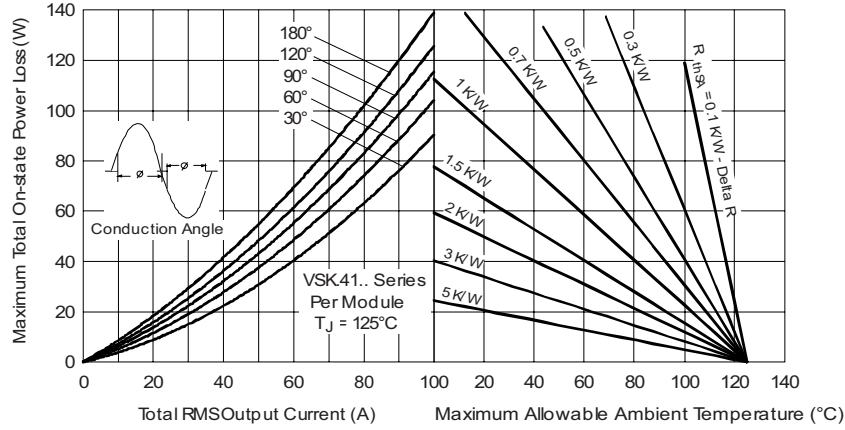


Fig. 7 - On-State Power Loss Characteristics

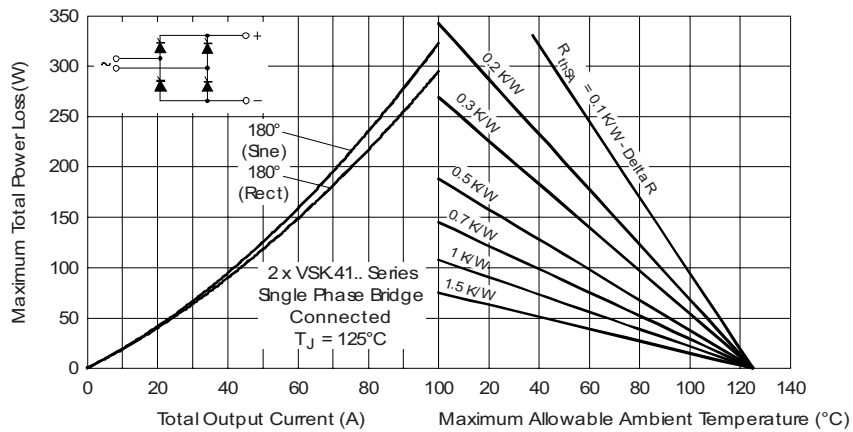


Fig. 8 - On-State Power Loss Characteristics

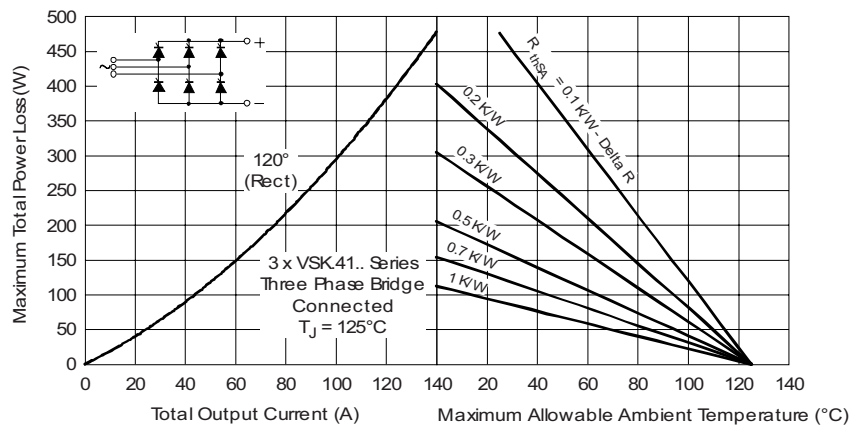


Fig. 9 - On-State Power Loss Characteristics

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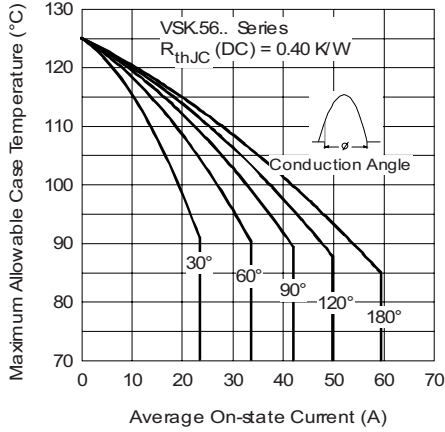


Fig. 10 - Current Ratings Characteristics

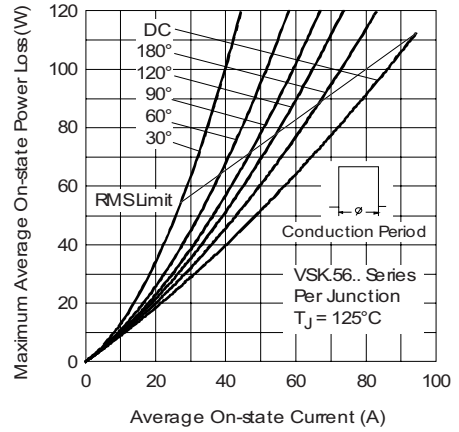


Fig. 13 - On-State Power Loss Characteristics

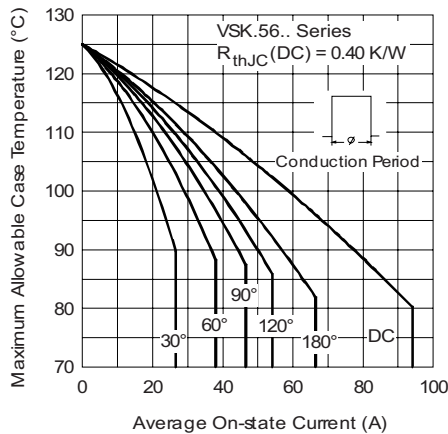


Fig. 11 - Current Ratings Characteristics

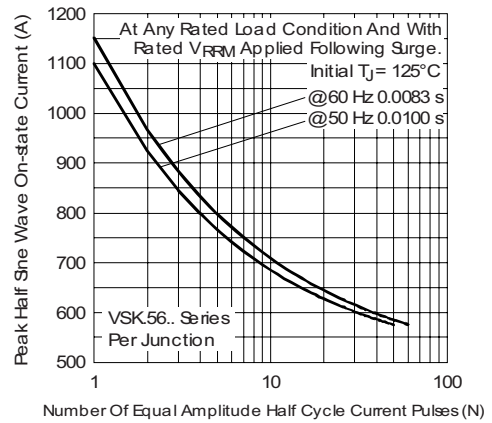


Fig. 14 - Maximum Non-Repetitive Surge Current

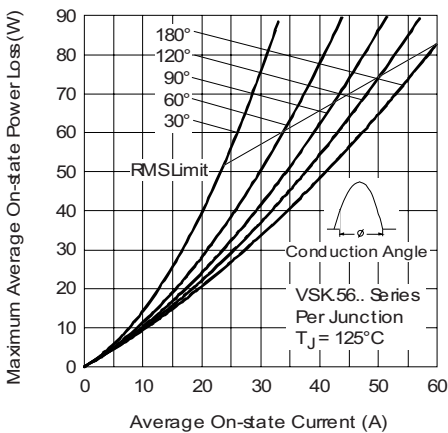


Fig. 12 - On-State Power Loss Characteristics

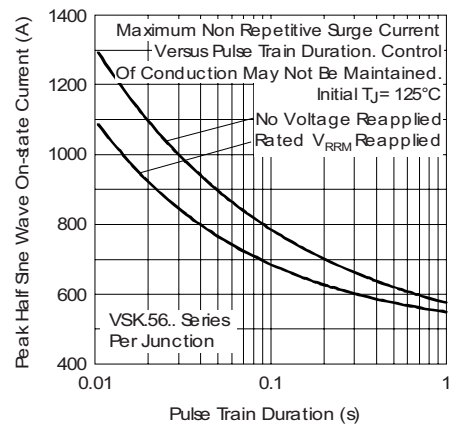


Fig. 15 - Maximum Non-Repetitive Surge Current



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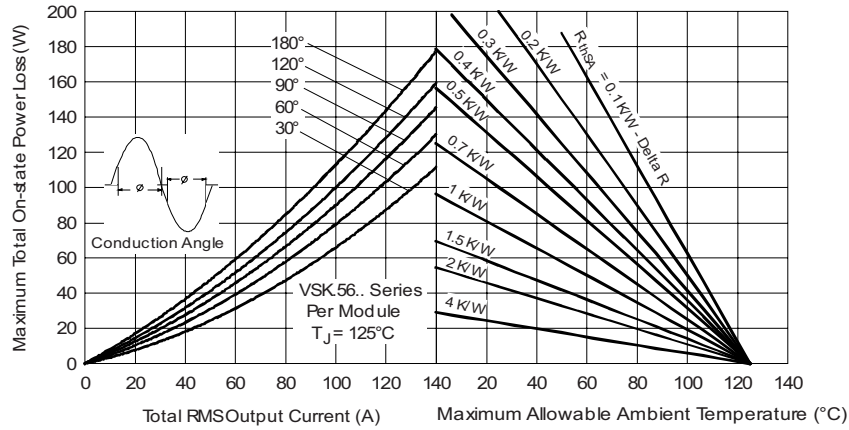


Fig. 16 - On-State Power Loss Characteristics

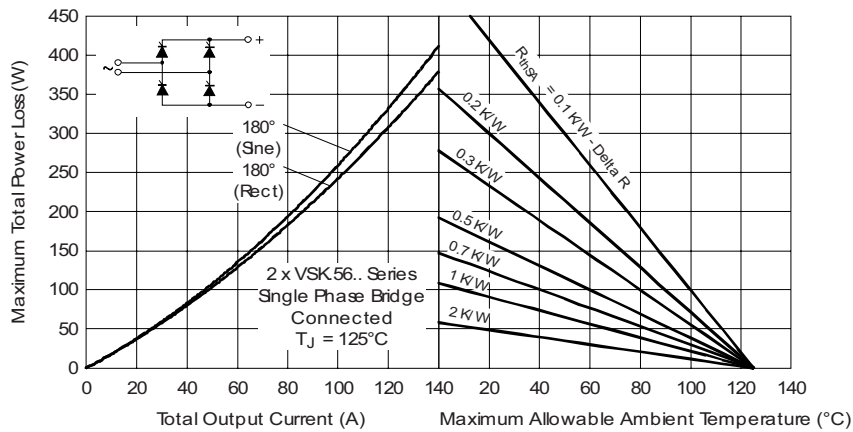


Fig. 17 - On-State Power Loss Characteristics

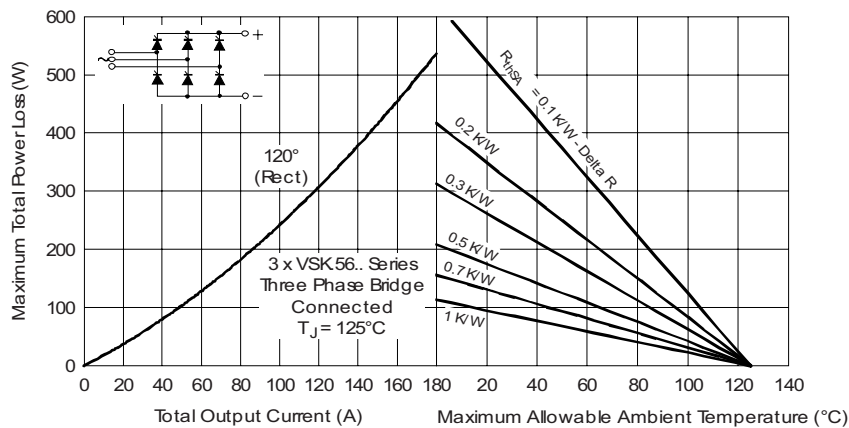


Fig. 18 - On-State Power Loss Characteristics

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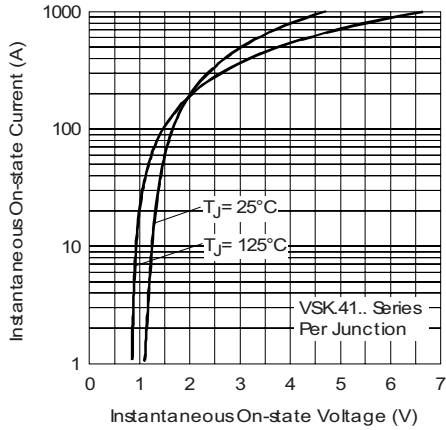


Fig. 19 - On-State Voltage Drop Characteristics

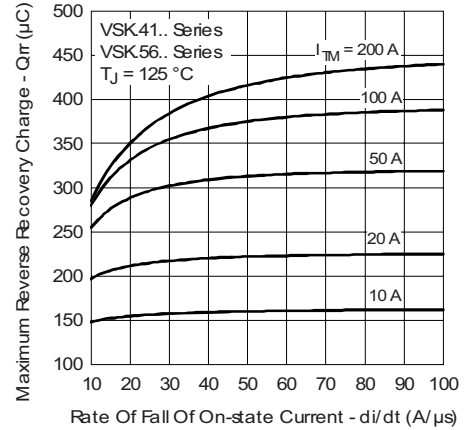


Fig. 21 - Recovery Charge Characteristics

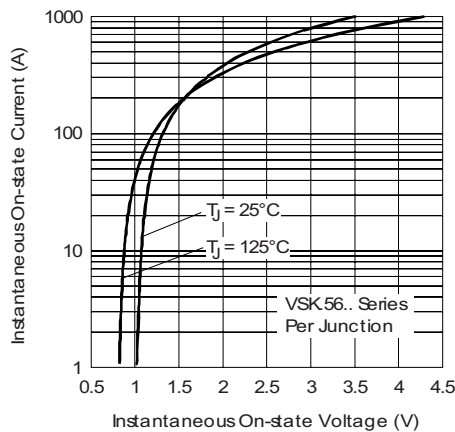


Fig. 20 - On-State Voltage Drop Characteristics

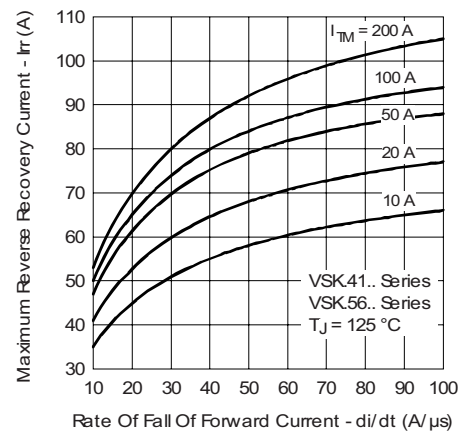


Fig. 22 - Recovery Current Characteristics

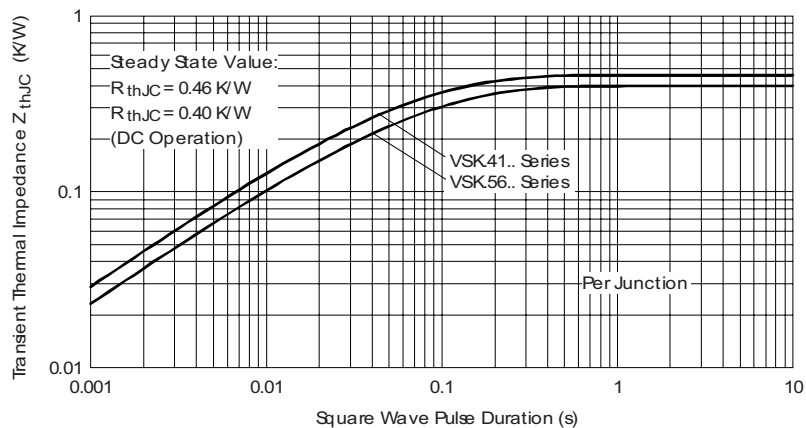


Fig. 23 - Thermal Impedance Z_{thJC} Characteristics



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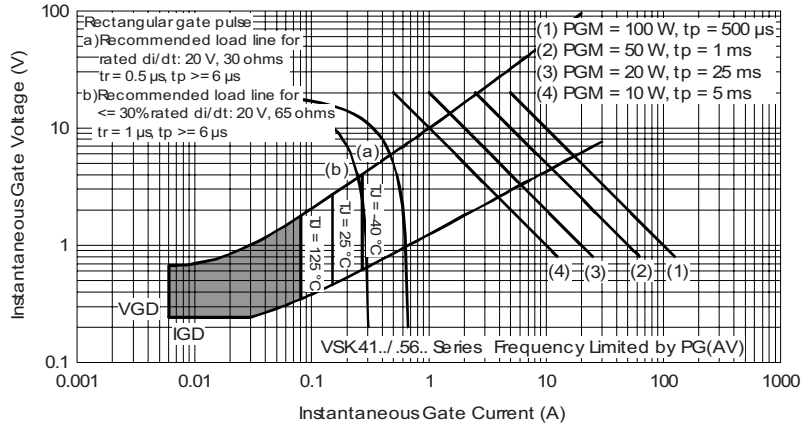


Fig. 24 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code	VSK	T	56	/	16	S90	P
	①	②	③		④	⑤	⑥

- ① - Module type
- ② - Circuit configuration (see end of datasheet)
- ③ - Current code ⁽¹⁾
- ④ - Voltage code (see Voltage Ratings table)
- ⑤ - dV/dt code: S90 = dV/dt 1000 V/μs
No letter = dV/dt 500 V/μs
- ⑥ - P = Lead (Pb)-free

⁽¹⁾ Available with no auxiliary cathode

(for details see dimensions - link at the end of datasheet)

To specify change: 41 to 42

56 to 57

e.g.: VSKT57/16P etc.

Note

- To order the optional hardware go to www.vishay.com/doc?95172

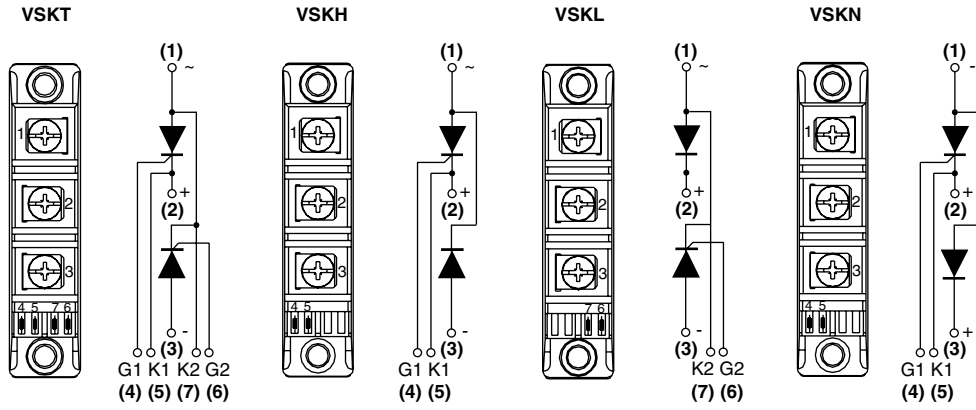
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CIRCUIT CONFIGURATION

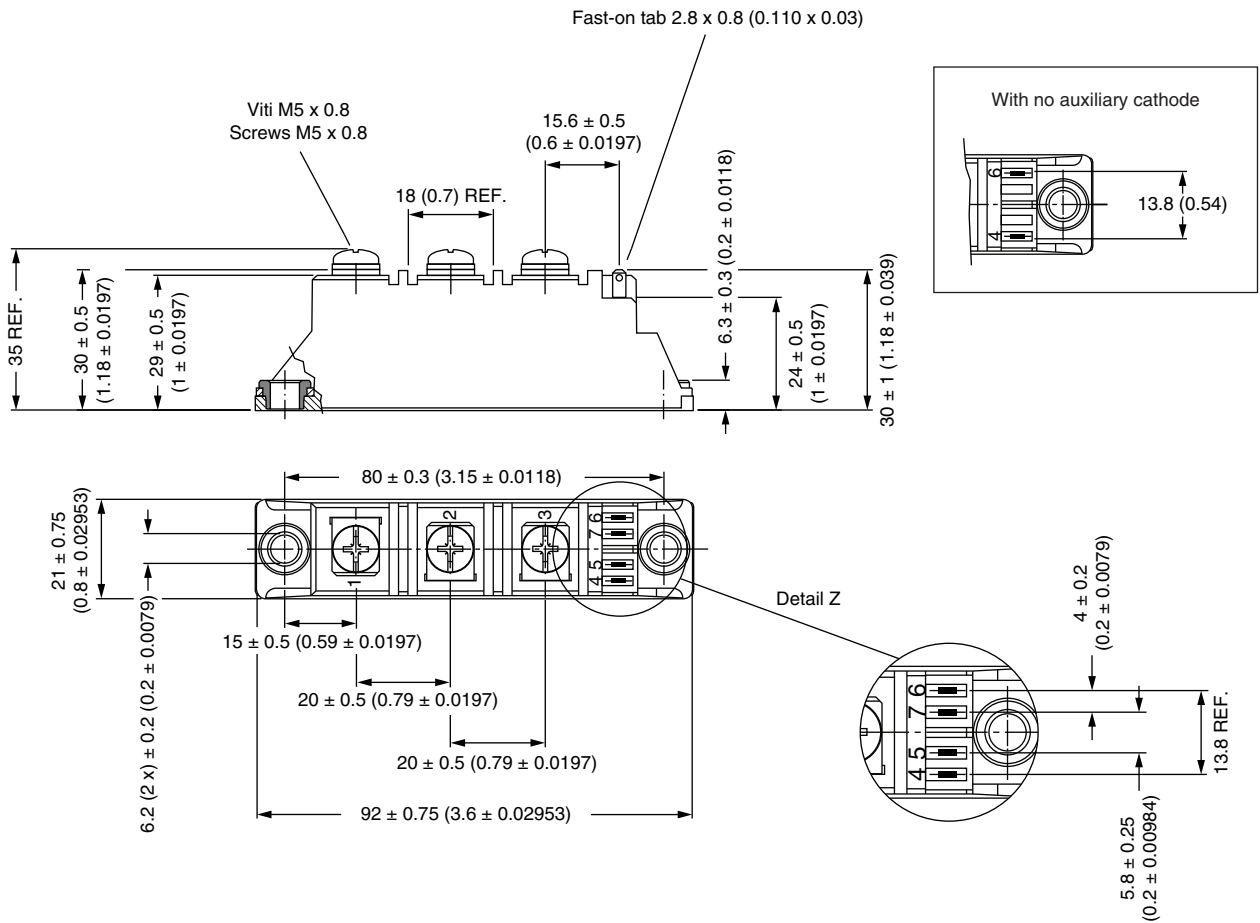


LINKS TO RELATED DOCUMENTS

Dimensions	http://www.vishay.com/doc?95085
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ADD-A-PAK SCR

DIMENSIONS in millimeters (inches)





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